Am27C080

Advanced Micro Devices

8 Megabit (1,048,576 x 8-Bit) CMOS EPROM

DISTINCTIVE CHARACTERISTICS

- Fast access time
 - 100 ns
- **■** Low power consumption
 - 100 μA maximum CMOS standby current
- JEDEC-approved pinout
 - Plug in upgrade of 1-, 2-, 4-Mbit EPROMs
 - Easy upgrade from 28-pin JEDEC EPROMs
- Single +5 V power supply

- ±10% power supply tolerance available
- 100% FlashriteTM programming
 - Typical programming time of less than 2 minutes
- Latch-up protected to 100 mA from -1 V to Vcc + 1 V
- High noise immunity
- Compact 32-pin DIP, PDIP, and PLCC packages

GENERAL DESCRIPTION

The Am27C080 is an 8 Mbit ultraviolet erasable programmable read-only memory. It is organized as 1,048K words by 8 bits per word, operates from a single +5 V supply, has a static standby mode, and features fast single address location programming. Products are available in windowed ceramic DIP and LCC packages as well as plastic one time programmable (OTP) PDIP and PLCC packages.

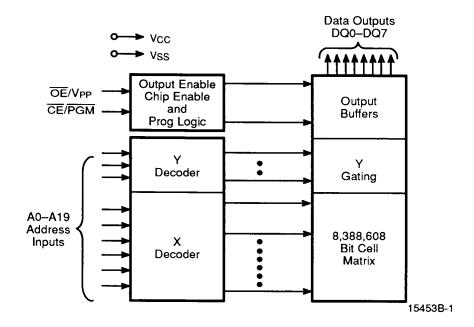
Typically, any byte can be accessed in less than 100 ns, allowing operation with high-performance microprocessors without any WAIT states. The Am27C080 offers separate Output Enable (OE) and Chip Enable (OE)

controls, thus eliminating bus contention in a multiple bus microprocessor system.

AMD's CMOS process technology provides high speed, low power, and high noise immunity. Typical power consumption is only 100 mW in active mode, and 100 μW in standby mode.

All signals are TTL levels, including programming signals. Bit locations may be programmed singly, in blocks, or at random. The Am27C080 supports AMD's Flashrite programming algorithm (100 µs pulses) resulting in typical programming times of less than 2 minutes.

BLOCK DIAGRAM



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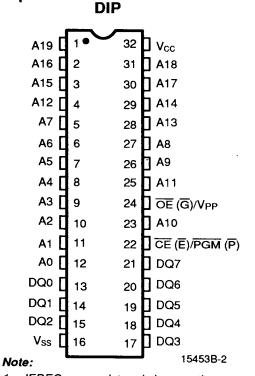
This document contains information on a product under development at Advanced Micro Devices, Inc. The information is intended to help you to evaluate this product. AMD reserves the right to change or discontinue work on this proposed product without notice.

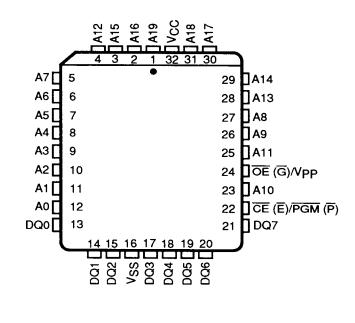


PRODUCT SELECTOR GUIDE

Family Part No.	Am27C080					
Ordering Part No: Vcc ± 5%	-105				-255	
Vcc ± 10%	-100	-120	-150	-200	-250	
Max Access Time (ns)	100	120	150	200	250	
CE (E) Access Time (ns)	100	120	150	200	250	
OE (G) Access Time (ns)	50	50	65	75	100	

CONNECTION DIAGRAMS Top View





PLCC

1. JEDEC nomenclature is in parentheses.

PIN DESIGNATIONS

A0-A19

= Address Inputs

CE (E)/PGM (P) = Chip Enable

DQ0-DQ7

= Data Inputs/Outputs

OE (G)/VPP

= Output Enable Input/

Program Supply Voltage

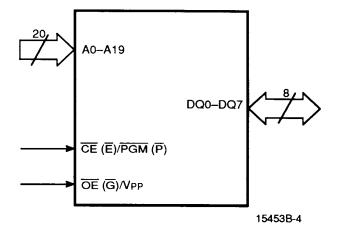
Vcc

= Vcc Supply Voltage

Vss

= Ground

LOGIC SYMBOL



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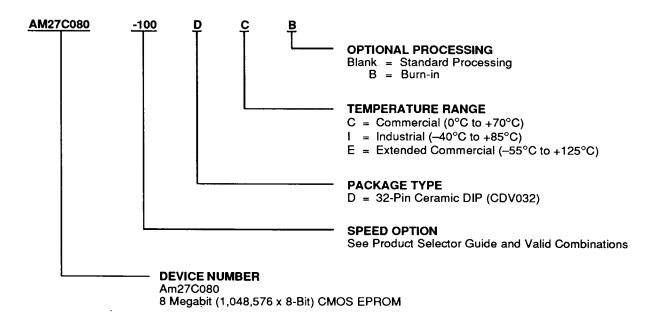
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Am27C080

ORDERING INFORMATION

EPROM Products

AMD Standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of:



Valid Combinations						
AM27C080-100	DC, DI					
AM27C080-105	00,01					
AM27C080-120	DC, DCB, DI, DIB					
AM27C080-150	DO DOD DI DID					
AM27C080-200	DC, DCB, DI, DIB, DE, DEB					
AM27C080-255						

Valid Combinations

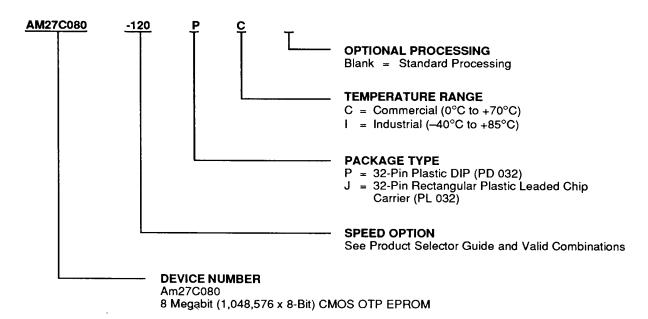
Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly released combinations.



ORDERING INFORMATION

OTP Products

AMD Standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of:



Valid Combinations						
AM27C080-120						
AM27C080-125						
AM27C080-150	PC, JC, PI, JI					
AM27C080-200						
AM27C080-255						

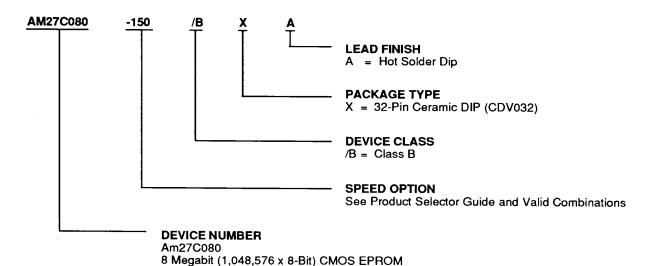
Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly released combinations.

ORDERING INFORMATION

Military APL Products

AMD products for Aerospace and Defense applications are available in several packages and operating ranges. APL (Approved Products List) products are fully compliant with MIL-STD-883 requirements. The order number (Valid Combination) is formed by a combination of:



Valid Combinations					
AM27C080-150					
AM27C080-200	/BXA				
AM27C080-250	1				

Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly released combinations.

Group A Tests

Group A tests consist of Subgroups 1, 2, 3, 7, 8, 9, 10, 11.



FUNCTIONAL DESCRIPTION

Erasing the Am27C080

In order to clear all locations of their programmed contents, it is necessary to expose the Am27C080 to an ultraviolet light source. A dosage of 15 W seconds/cm² is required to completely erase an Am27C080. This dosage can be obtained by exposure to an ultraviolet lamp—wavelength of 2537 Å—with intensity of 12,000 $\mu\text{W/cm}^2$ for 15 to 20 minutes. The Am27C080 should be directly under and about one inch from the source and all filters should be removed from the UV light source prior to erasure.

It is important to note that the Am27C080 and similar devices will erase with light sources having wavelengths shorter than 4000 Å. Although erasure times will be much longer than with UV sources at 2537 Å, exposure to fluorescent light and sunlight will eventually erase the Am27C080 and exposure to them should be prevented to realize maximum system reliability. If used in such an environment, the package window should be covered by an opaque label or substance.

Programming the Am27C080

Upon delivery or after each erasure the Am27C080 has all 8,388,608 bits in the "ONE" or HIGH state. "ZEROs" are loaded into the Am27C080 through the procedure of programming.

The programming mode is entered when 12.75 V \pm 0.25 V is applied to the $\overline{OE/V_{PP}}$ and $\overline{CE/PGM}$ is at V_{IL} .

For programming, the data to be programmed is applied 8 bits in parallel to the data output pins.

The Flashrite algorithm reduces programming time by using 100 μ s programming pulses and by giving each address only as many pulses as is necessary in order to reliably program the data. After each pulse is applied to a given address, the data in that address is verified. If the data does not verify, additional pulses are given until it verifies or the maximum is reached. This process is repeated while sequencing through each address of the Am27C080. This part of the algorithm is done at $V_{CC} = 6.25 \text{ V}$ to assure that each EPROM bit is programmed to a sufficiently high threshold voltage. After the final address is completed, the entire EPROM memory is verified at $V_{CC} = V_{PP} = 5.25 \text{ V}$.

Please refer to Section 6.0 for programming flow charts and characteristics.

Program Inhibit

Programming of multiple Am27C080 in parallel with different data is also easily accomplished. Except for $\overline{\text{CE/PGM}}$, all like inputs of the parallel Am27C080 may be common. A TTL low-level program pulse applied to an Am27C080 $\overline{\text{CE/PGM}}$ input and $\overline{\text{OE/V}_{PP}} = 12.75 \text{ V} \pm$

0.25 V, will program that Am27C080. A high-level CE/PGM input inhibits the other Am27C080 devices from being programmed.

Program Verify

A verify should be performed on the programmed bits to determine that they were correctly programmed. The verify should be performed with $\overline{\text{CE}/\text{PGM}}$ at V_{IL} and $\overline{\text{OE}/\text{VPP}}$ at V_{IL} .

Auto Select Mode

The auto select mode allows the reading out of a binary code from an EPROM that will identify its manufacturer and type. This mode is intended for use by programming equipment for the purpose of automatically matching the device to be programmed with its corresponding programming algorithm. This mode is functional in the $25^{\circ}\text{C} \pm 5^{\circ}\text{C}$ ambient temperature range that is required when programming the Am27C080.

To activate this mode, the programming equipment must force 12.0 V \pm 0.5 V open address the A9 of the Am27C080. Two identifier bytes may then be sequenced from the device outputs by toggling address line A0 from V_{IL} to V_{IH}. All other address lines must be held at V_{IL} during auto select mode.

Byte 0 (A0 = $V_{\rm IL}$) represents the manufacturer code, and byte 1 (A0 = $V_{\rm IH}$), the device code. For the Am27C080, these two identifier bytes are given in the Mode Select Table. All identifiers for manufacturer and device codes will possess odd parity, with the MSB (DQ7) defined as the parity bit.

Read Mode

The Am27C080 has two control functions, both of which must be logically satisfied in order to obtain data at the outputs. Chip Enable ($\overline{\text{CE/PGM}}$) is the power control and should be used for device selection. Output Enable ($\overline{\text{OE}}/\text{V}_{\text{PP}}$) is the output control and should be used to gate data to the output pins, independent of device selection. Assuming that addresses are stable, address access time (t_{ACC}) is equal to the delay from $\overline{\text{CE/PGM}}$ to output (t_{CE}). Data is available at the outputs toe after the falling edge of $\overline{\text{OE}}/\text{V}_{\text{PP}}$, assuming that $\overline{\text{CE/PGM}}$ has been LOW and addresses have been stable for at least t_{ACC} — t_{OE} .

Standby Mode

The Am27C080 has a CMOS standby mode which reduces the maximum V_{CC} current to 100 μ A. It is placed in CMOS-standby when $\overline{\text{CE/PGM}}$ is at V_{CC} \pm 0.3 V. The Am27C080 also has a TTL-standby mode which reduces the maximum V_{CC} current to 1.0 mA. It is placed in TTL-standby when $\overline{\text{CE/PGM}}$ is at V_{IH}. When in standby mode, the outputs are in a high-impedance state, independent of the $\overline{\text{OE/VPP}}$ input.

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Output OR-Tieing

To accommodate multiple memory connections, a twoline control function is provided to allow for:

- Low memory power dissipation
- Assurance that output bus connection will not occur

It is recommended that $\overline{\text{CE/PGM}}$ be decoded and used as the primary device-selecting function, while $\overline{\text{OE/V_{PP}}}$ be made a common connection to all devices in the array and connected to the READ line from the system control bus. This assures that all deselected memory devices are in low-power standby mode and that the output pins are only active when data is desired from a particular memory device.

System Applications

During the switch between active and standby conditions, transient current peaks are produced on the rising and falling edges of Chip Enable. The magnitude of these transient current peaks is dependent on the output capacitance loading of the device. At a minimum, a 0.1- μ F ceramic capacitor (high frequency, low inherent inductance) should be used on each device between Vcc and Vss to minimize transient effects. In addition, to overcome the voltage drop caused by the inductive effects of the printed circuit board traces on EPROM arrays, a 4.7- μ F bulk electrolytic capacitor should be used between Vcc and Vss for each eight devices. The location of the capacitor should be close to where the power supply is connected to the array.

MODE SELECT TABLE

Mode	Pins	CE/PGM	ŌĒ/Vpp	A0	A 9	Outputs
Read		VIL	VIL	A 0	A9	Dout
Output Disable		Х	ViH	Х	Х	Hi-Z
Standby (TTL)		Vıн	Х	Х	Х	Hi-Z
Standby (CMOS)	•	Vcc + 0.3 V	Х	Х	Х	Hi-Z
Program		VIL	Vpp	A 0	A9	Din
Program Verify		VIL	VIL	Х	Х	Dout
Program Inhibit		Vін	VPP	Х	Х	Hi-Z
Auto Select (Note 3)	Manufacturer Code	ViL	VIL	VIL	Vн	01H
(14019-3)	Device Code	VIL	VIL	ViH	VH	1CH

Notes:

- 1. $V_{IH} = 12.0 \pm 0.5 \text{ V}$
- 2. $X = Either V_{IH} or V_{IL}$
- 3. $A1-A8 = A10-A19 = V_{IL}$
- 4. See DC Programming Characteristics for VPP voltage during programming.



ABSOLUTE MAXIMUM RATINGS

Storage Temperature OTP Products65°C to +125°C All Other Products65°C to +150°C
Ambient Temperature with Power Applied55°C to +125°C
Voltage with Respect To V _{SS} All pins except A9,
V _{PP} ,V _{CC} 0.6 V to V _{CC} + 0.6 V
A9 and V _{PP} 0.6 V to +13.5 V
V _{CC} 0.6 V to +7.0 V

Notes:

- 1. Minimum DC voltage on input or I/O pins is -0.5 V. During transitions, the inputs may overshoot V_{SS} to -2.0 V for periods of up to 20 ns. Maximum DC voltage on input and I/O pins is $V_{CC} + 0.5$ V which may overshoot to $V_{CC} + 2.0$ V for periods up to 20 ns.
- For A9 and V_{PP} the minimum DC input is -0.5 V. During transitions, A9 and V_{PP} may overshoot V_{SS} to -2.0 V for periods of up to 20 ns. A9 and V_{PP} must not exceed 13.5 V for any period of time.

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure of the device to absolute maximum rating conditions for extended periods may affect device reliability.

OPERATING RANGES

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over operating range unless otherwise specified. (Notes 1, 2 and 4) (for APL Products, Group A, Subgroups 1, 2, 3, 6 and 7 are tested unless otherwise noted)

Parameter Symbol	Parameter Description	Test Conditions		Min	Max	Unit
Vон	Output HIGH Voltage	loн = -400 μA		2.4		٧
Vol.	Output LOW Voltage	IOL = 2.1 mA			0.45	٧
VIH	Input HIGH Voltage		2.0	Vcc + 0.5	V	
VIL	Input LOW Voltage		-0.5	+0.8	٧	
I Lı	Input Load Current	VIN = 0 V to +Vcc	· · · · · · · · · · · · · · · · · · ·	1.0	μА	
llo	Output Leakage Current	Vout = 0 V to +Vcc		5.0	μА	
Icc ₁	Vcc Active Current	CE = V _{IL} , f = 5 MHz, C/I Devices			40	μА
	(Note 3)	IOUT = 0 mA		50	μ.,	
lcc2	Vcc TTL Standby Current	CE = VIH		1.0	mA	
Іссз	Vcc CMOS Standby Current	CE = Vcc ± 0.3 V		100	μА	
IPP1	VPP Current During Read	CE = OE = VIL, VPP = VCC		100	μА	

Notes:

- 1. VCC must be applied simultaneously or before VPP, and removed simultaneously or after VPP.
- 2. Caution: The Am27C080 must not be removed from (or inserted into) a socket when VCC or VPP is applied.
- 3. ICC1 is tested with $\overline{OE}/V_{PP} = V_{IH}$ to simulate open outputs.
- 4. Minimum DC Input Voltage is -0.5 V. During transitions, the inputs may overshoot to -2.0 V for periods less than 20 ns. Maximum DC Voltage on output pins is V_{CC} + 0.5 V, which may overshoot to V_{CC} + 2.0 V for periods less than 20 ns.

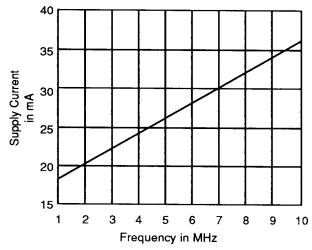


Figure 1. Typical Supply Current vs. Frequency Vcc = 5.5 V, T = 25°C

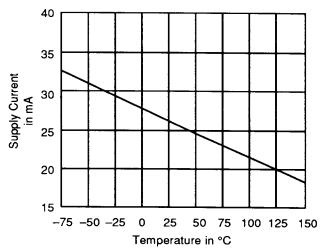


Figure 2. Typical Supply Current vs. Temperature Vcc = 5.5 V, f = 5 MHz

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15453B-5



CAPACITANCE

Parameter			CDV	CDV032		CDV032 PL 032		PD 032		
Symbol	Parameter Description	Test Conditions	Тур	Max	Тур	Max	Тур	Max	Unit	
CIN	Input Capacitance	VIN = 0	7	12	7	12	7	12	pF	
Соит	Output Capacitance	Vout = 0	12	16	12	16	12	16	pF	

Notes:

- 1. This parameter is only sampled and not 100% tested.
- 2. $T_A = +25^{\circ}C$, f = 1 MHz

SWITCHING CHARACTERISTICS over operating range unless otherwise specified (Notes 1, 3 and 4) (for APL Products, Group A, Subgroups 9,10 and 11 are tested unless otherwise noted)

Parameter Symbols					Am27C080					
JEDEC	Standard	Parameter Description	Test Conditions		-105 -100	-120	-150	-200	-255 -250	Unit
tavov	tACC	Address to	CE = OE =	Min		_	_	_	_	
		Output Delay	VIL	Max	100	120	150	200	250	ns
tELQV	tce	Chip Enable to	OE = VIL	Min	_	_		_	_	
		Output Delay		Max	100	120	150	200	250	ns
tGLQV	toe	Output Enable to	CE = VIL	Min		_	_	_	_	
		Output Delay		Max	50	50	55	60	60	ns
tehoz	tDF	Chip Enable HIGH or		Min		_			_	
tGHQZ	(Note 2)	Output Enable HIGH, whichever comes first, to Output Float		Max	40	40	40	40	60	ns
taxqx	tон	Output Hold from		Min	0	0	0	0	0	
		Addresses, CE, or OE, whichever occurred first		Max	_	_		-	_	ns

Notes:

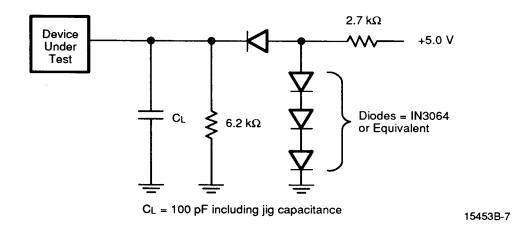
- 1. V_{CC} must be applied simultaneously or before V_{PP} , and removed simultaneously or after V_{PP} .
- 2. This parameter is only sampled and not 100% tested.
- 3. Caution: The Am27C080 must not be removed from (or inserted into) a socket or board when VPP or VCC is applied.
- 4. Output Load: 1 TTL gate and C_L = 100 pF

Input Rise and Fall Times: 20 ns Input Pulse Levels: 0.45 V to 2.4 V

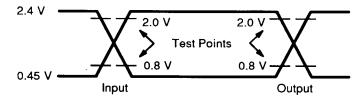
Timing Measurement Reference Level: 0.8 V and 2 V inputs and outputs

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SWITCHING TEST CIRCUIT



SWITCHING TEST WAVEFORM



AC Testing: Inputs are driven at 2.4 V for a logic "1" and 0.45 V for a logic "0". Input pulse rise and fall times are ≤ 20 ns. 15453B-8

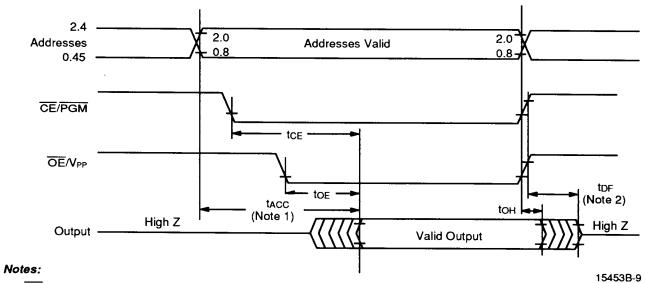


KEY TO SWITCHING WAVEFORMS

WAVEFORM	INPUTS	OUTPUTS
	Must Be Steady	Will Be Steady
	May Change from H to L	Will Be Changing from H to L
	May Change from L to H	Will Be Changing from L to H
	Don't Care Any Change Permitted	Changing State Unknown
>>→	Does Not Apply	Center Line is High Impedence "Off" State

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SWITCHING WAVEFORMS



- 1. \overline{OE}/V_{PP} may be delayed up to t_{ACC} t_{OE} after the falling edge of the addresses without impact on t_{ACC} .
- 2. t_{OE} is specified from \overline{OE} or \overline{CE} , whichever occurs first.